

1N4001G - 1N4007G BY133G

GLASS PASSIVATED JUNCTION SILICON RECTIFIERS

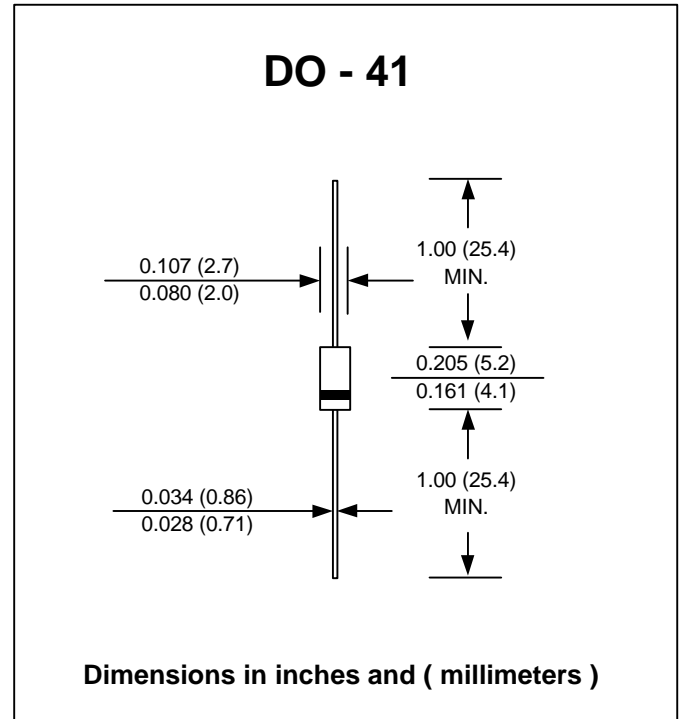
PRV : 50 - 1000 Volts
Io : 1.0 Ampere

FEATURES :

- * Glass passivated chip
- * High current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * **Pb / RoHS Free**

MECHANICAL DATA :

- * Case : DO-41 Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 0.34 gram



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

RATING	SYMBOL	1N 4001G	1N 4002G	1N 4003G	1N 4004G	1N 4005G	1N 4006G	1N 4007G	BY 133G	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	1300	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	910	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	1300	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 75 °C	I _{F(AV)}	1.0								A
Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	30								A
Maximum Forward Voltage at I _F = 1.0 Amp.	V _F	1.0								V
Maximum DC Reverse Current Ta = 25 °C at rated DC Blocking Voltage Ta = 100 °C	I _R	5.0								μA
	I _{R(H)}	50								μA
Typical Junction Capacitance (Note1)	C _J	8								pF
Typical Thermal Resistance (Note2)	R _{θJA}	45								°C/W
Junction Temperature Range	T _J	- 65 to + 175								°C
Storage Temperature Range	T _{STG}	- 65 to + 175								°C

Notes : (1) Measured at 1.0 MHz and applied reverse voltage of 4.0VDC
(2) Thermal resistance from Junction to Ambient at 0.375" (9.5mm) Lead Lengths, P.C. Board Mounted.

RATING AND CHARACTERISTIC CURVES (1N4001G - BY133G)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

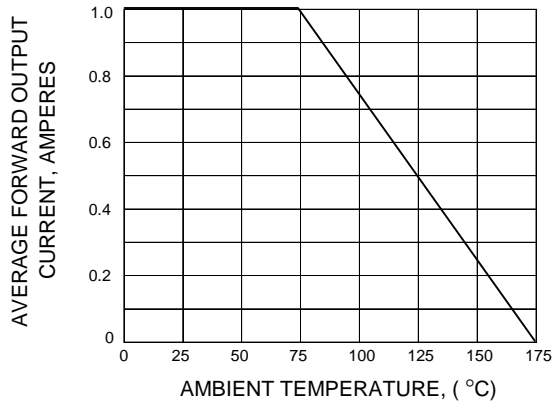


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

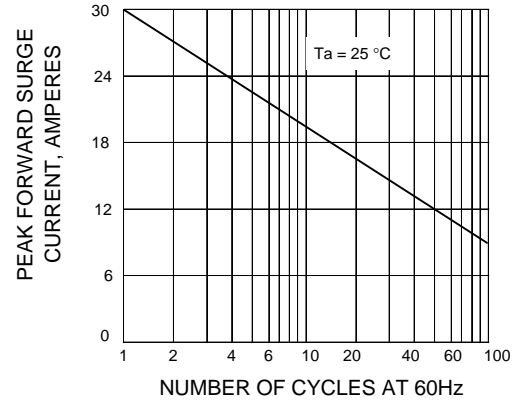


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

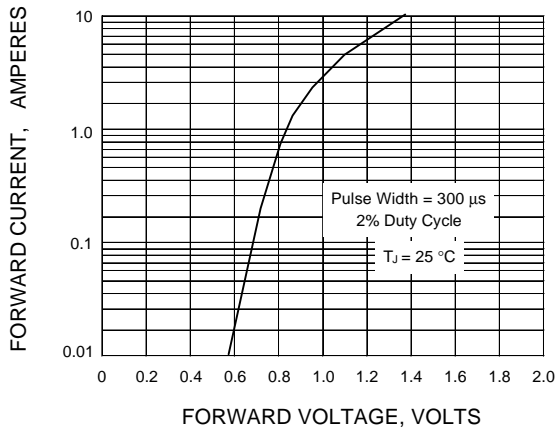


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

